GSDMB10F

Bridge Rectifier

Product Description

Reverse Voltage 1000V. Forward Current 0.8A

Features

- Glass Passivated Junction
- RoHS Compliant and Halogen Free

Mechanical Data

- MBS Package
- High Temperature Soldering Guaranteed 260°C, 10s.

Package and Pin Assignment



Ordering and Marking Information

Ordering Information				
Part Number	V _{RRM}	Marking Code	Quantity/Reel	
GSDMB10F	1000	MB10S	5000 PCS	
GSDMB10F				
- Product Code:	- Voltage Code:	- Green	Level:	
GSDMB	10 stands for Maximu	ım F for R	oHS Compliant and	
	repetitive peak revers	se voltage. Haloge	n Free	
	Marking Informa	ation		



MB10S

Electrical Characteristics (T_A = 25°C unless otherwise specified.)

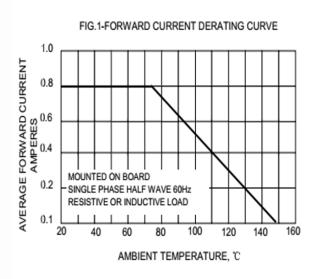
Symbol	Conditions	MB10	Unit
V _{RRM}	Maximum Recurrent Peak Reverse Voltage	1000	V
V_{RMS}	Maximum RMS Voltage	700	V
V _{DC}	Maximum DC Blocking Voltage	1000	V
I _{F(AV)}	Maximum Average Forward Rectified Current	0.8	А
I _{FSM}	Peak Forward Surge Current (8.3ms Single Half Sinewave)	30	А
VF	Maximum Forward Voltage at 0.8A	1.1	V
	Maximum T _J = 25°C	5	μΑ
I _R	Leakage Current at rated V _R T _J = 125°C	100	μΑ
$R_{\theta JA}$	Typical Thermal Resistance ⁽³⁾	62.5	°C/W
TJ	Operating Junction Temperature Range	-55 to +150	°C
Тѕтс	Storage Temperature Range	-55 to +150	°C

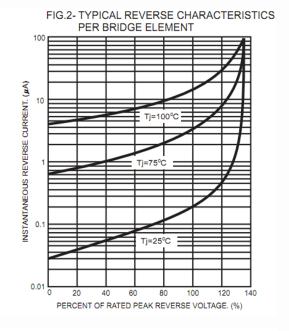
NOTES:

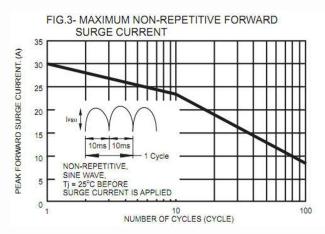
- Measured with I_F=0.5A, I_R=1A, Irr=0.25A.
 Mounted with 0.2 x 0.2" (5.0 x 5.0mm) Copper Pad Areas

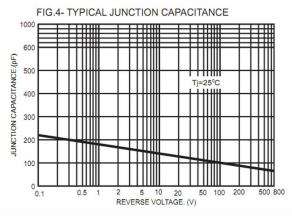


Typical Characteristics (T_A = 25°C unless otherwise specified.)











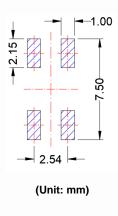


MBS

Package Dimension

GAUGE PLANE

Recommended Land Pattern



	Dimensions				
Symbol	Millimeters		Inches		
Syllibol	Min	Max	Min	Max	
Α	2.40	3.00		0.118	
A1	0.05	0.20	0.002	0.008	
A2	1.80	2.80	0.071	0.110	
b	0.43	0.80	0.017	0.031	
С	0.15	0.41	0.006	0.016	
D	4.50	5.00	0.177	0.197	
E	6.40	7.00	0.252	0.276	
E1	3.65	4.25	0.144	0.167	
е	2.54 BSC		0.100 BSC		
θ	0 °	8 °	0 °	8 °	

NOTE:

Dimensions are exclusive of Burrs, Mold Flash & Tie Bar extrusions.



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